

**Silicon Schottky Barrier Diode****FEATURES**

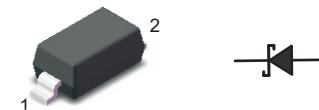
- Metal silicon junction, majority carrier conduction
- Ideal for used in detection or for switching on the radio, TV, etc.

**MECHANICAL DATA**

- Case: SOD-123
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 16mg/0.00056oz

**PINNING**

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View  
Marking Code: L60  
Simplified outline SOD-123 and symbol

**Maximum Ratings and Electrical characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbols	1N60PW	Units
Peak Reverse Voltage	$V_{RM}$	45	V
Reverse Voltage	$V_R$	20	V
Average Rectified Output Current	$I_o$	50	mA
Peak Forward Current	$I_{FM}$	150	mA
Surge Forward Current	$I_{surge}$	500	mA
Forward Current at $V_F < 1V$	$I_F$	4	mA
Reverse Current at $V_R = 10V$	$I_R$	50	uA
Total Capacitance at $f=1MHz, V_R=1V$	$C_{tot}$	38	pF
Rectification efficiency at $V_i = 2 V_{RMS}, R = 5 K\Omega$	$\eta$	55	%
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$T_{stg}$	-55 ~ +150	°C

Fig.1 Forward Characteristics

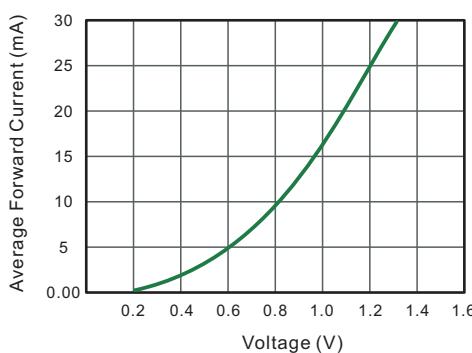
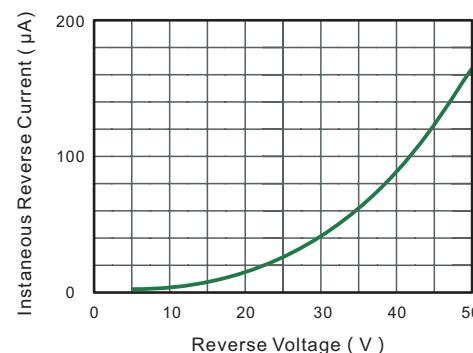


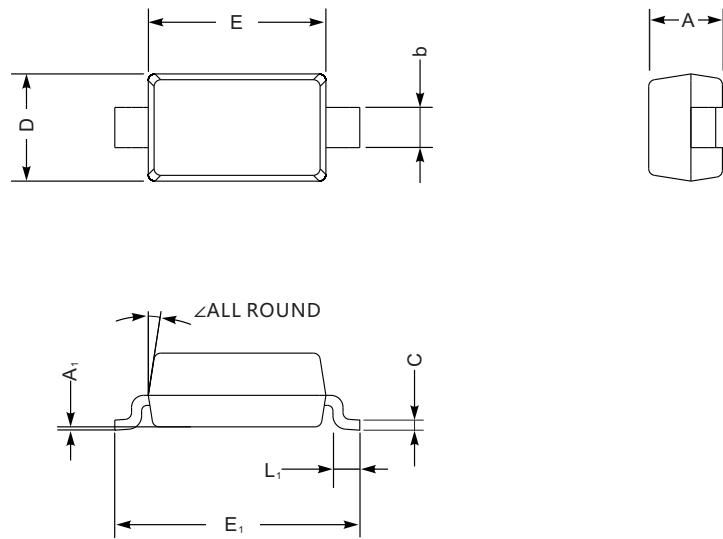
Fig.2 Typical Reverse Characteristics



## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



SOD-123 mechanical data

UNIT		A	C	D	E	E <sub>1</sub>	L <sub>1</sub>	b	A <sub>1</sub>	∠
mm	max	1.3	0.22	1.8	2.8	3.9	0.45	0.7	0.2	9°
	min	0.9	0.09	1.5	2.5	3.6	0.25	0.5	—	
mil	max	51	8.7	71	110	154	18	28	8	9°
	min	35	3.5	59	98	142	10	20	—	

## The recommended mounting pad size

